•			Timo etamo	
L Number	Hits	Search Text	DB USPAT;	Time stamp 2002/05/17 11:22
-	696	(438/400).ccls. and @ad<=20011206	US-PGPUB;	2002/03/1/ 11:22
			EPO; JPO;	i !
			DERWENT;	
			IBM_TDB	_ !
_	6	((438/400).ccls. and @ad<=20011206) and	USPAT;	2002/05/17 11:26
		ONO	US-PGPUB;	
			EPO; JPO;	_
			DERWENT;	
			IBM_TDB	2002/05/17 12:35
-	0	@ad<=20011206 and 'ONO structure' with	USPAT; US-PGPUB;	2002/03/17 12:33
		'buffer layer'	EPO; JPO;	
			DERWENT;	
			IBM TDB	
ļ	290	@ad<=20011206 and 'ONO structure'	USPAT;	2002/05/17 12:01
-	290	ead(-20011200 and one berassars	US-PGPUB;	1
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	160	@ad<=20011206 and 'Oxide' with 'SiON' with	USPAT;	2002/05/17 12:31
		'SiN' with 'SiON' with 'Oxide'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	, 2002/05/17 12:40
-	3	@ad<=20011206 and 'ONO structure' and	USPAT;	2002/05/17 12:40
		'buffer layer'	US-PGPUB;	
			EPO; JPO; DERWENT;	
	-		IBM TDB	
	,	@ad<=20011206 and 'multi dielectric layer'	USPAT;	2002/05/17 12:43
-	1	and 'memory'	US-PGPUB;	2002/03/1. 12:13
		and memory	EPO; JPO;	
			DERWENT;	
			IBM TDB	i
_	26	@ad<=20011206 and 'multi' adj 'dielectric'	USPAT;	2002/05/17 12:47
	20	and 'memory'	US-PGPUB;	
		,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	0	@ad<=20011206 and 'O-SiON-N-SiON-O'	USPAT;	2002/05/17 12:49
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		0 14 00011006 2 2 2 2 0107 2	<pre>IBM_TDB USPAT;</pre>	2002/05/17 12:55
-	1393	@ad<=20011206 and oxide and SiON and	US-PGPUB;	2002/03/11 12.33
		Nitride and SiON and oxide	EPO; JPO;	
			DERWENT;	
			IBM TDB	
1_		@ad<=20011206 and oxide adj SiON adj	USPAT;	2002/05/17 12:56
1 -	-	Nitride adj SiON adj oxide	US-PGPUB;	
		Historia day ordi. day onida	EPO; JPO;	
	1		DERWENT;	
			IBM_TDB	
_	300	@ad<=20011206 and 'oxide' with 'SiON' with	USPĀT;	2002/05/17 14:31
		'nitride' with 'SiON' with 'oxide'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	2002/10/20 00:13
-	107	(@ad<=20011206 and 'oxide' with 'SiON'	USPAT;	2002/10/28 09:13
		with 'nitride' with 'SiON' with 'oxide')	US-PGPUB;	
		and memory	EPO; JPO;	
			DERWENT;	
		0.14 00011006 and (420/770) and	IBM_TDB USPAT;	2002/05/17 14:32
-	540	@ad<=20011206 and (438/778).ccls.	US-PGPUB;	2002/03/17 14.32
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
1	1			

Search History 10/28/02 2:00:06 PM Page 1 C:\APPS\east\workspaces\Dielectric Formation or SOG\10002978 ONO with Buffer layers.wsp

ř.	2862	((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 08:49
_	2802	or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	2002/10/28 08.49
		or (438/770) or (438/775)).CCLS.	EPO; JPO;	
		OI (430/770) OI (430/773)).CCLS.	DERWENT;	
			IBM TDB	
	2256	//257/224\ or /257/214-215\ or /257/406\	USPAT;	2002/10/28 08:41
-	2356			2002/10/28 08:41
		or (257/410)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	1
	_		IBM_TDB	
-	7	(((100),) 01 (100), 01 (100), 100 (100)	USPAT;	2002/10/28 08:59
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'silane' with 'nitrogen	DERWENT;	
		oxide'	IBM TDB	ŧ
-	6328	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:03
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
	-	or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'SiON' or 'silicon	DERWENT;	
		oxynitride'	IBM TDB	
	0	1 2		2002/10/20 00:04
_	1	((((()))))	USPAT;	2002/10/28 09:04
1		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and SiH4 with N20 with NH3	DERWENT;	
			IBM TDB	
-	8	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:09
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'SiON' with 'deposition'	DERWENT;	
		edax-20011200 and Sion with deposition	IBM TDB	
	448	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:11
_	440			2002/10/28 09:11
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'ammonia'	DERWENT;	
			IBM_TDB	
-	190		USPAT;	2002/10/28 09:11
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	I
		@ad<=20011206 and 'ammonia' and 'silane'	DERWENT;	1
			IBM TDB	
_	194	@ad<=20011206 and 'ammonia' and 'silane'	USPAT;	2002/10/28 09:16
		and 'nitrogen oxide'	US-PGPUB;	2002/10/20 03.10
			EPO; JPO;	
			DERWENT;	
		0.14.00011006	IBM_TDB	0000/10/55 55 55
_	359		USPAT;	2002/10/28 09:13
		'nitride' with 'SiON' with 'oxide'	US-PGPUB;	t.
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	27	@ad<=20011206 and 'ammonia' same 'silane'	USPAT;	2002/10/28 09:19
		same 'nitrogen oxide'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
			םחד דחם	<u> </u>